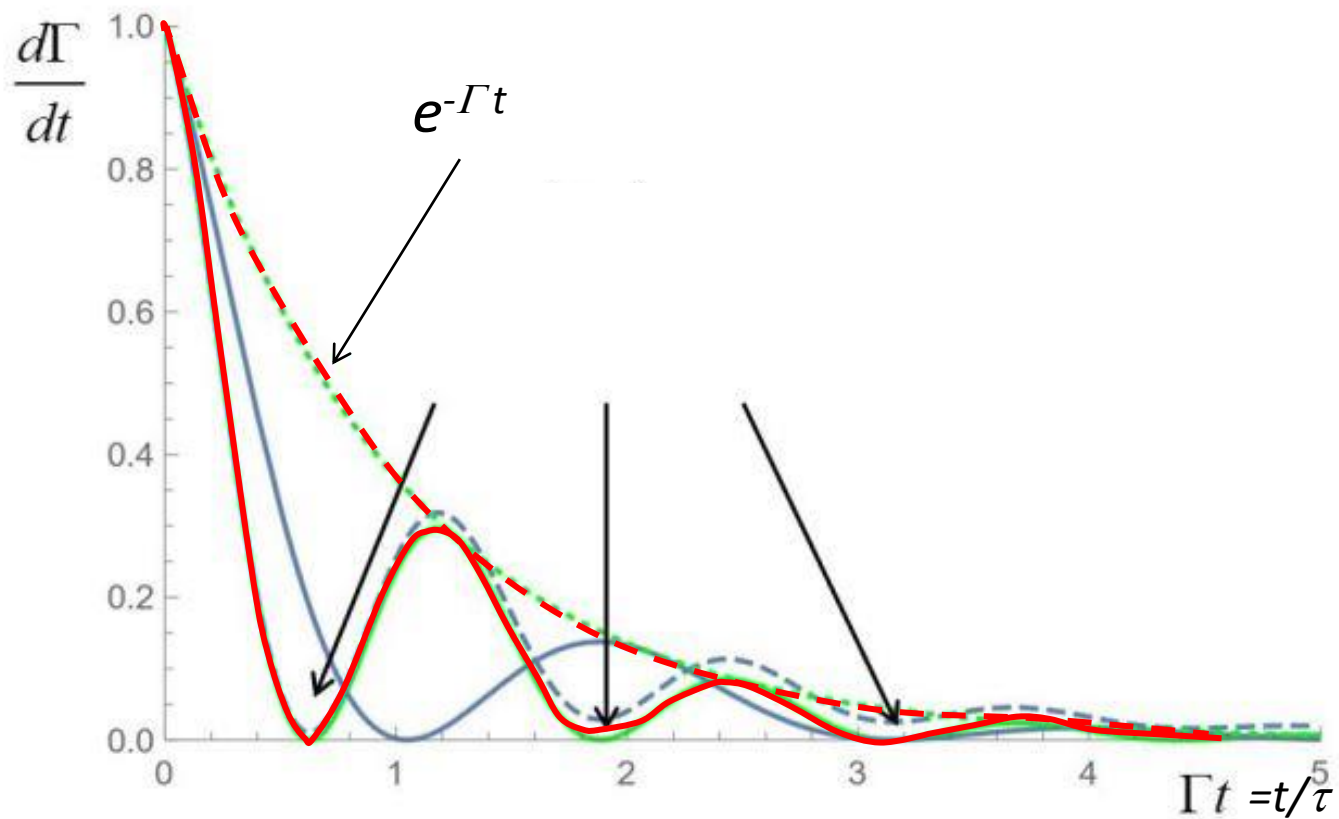
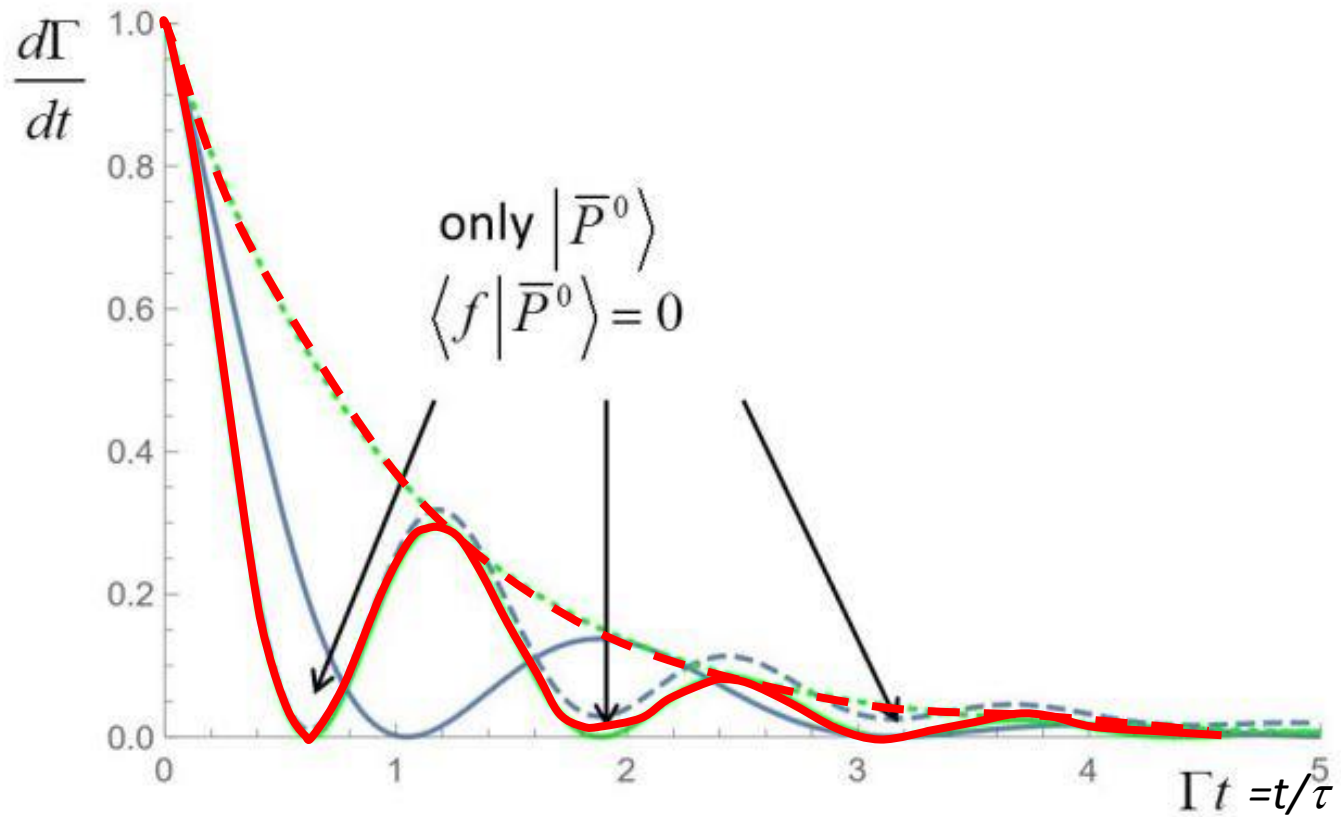


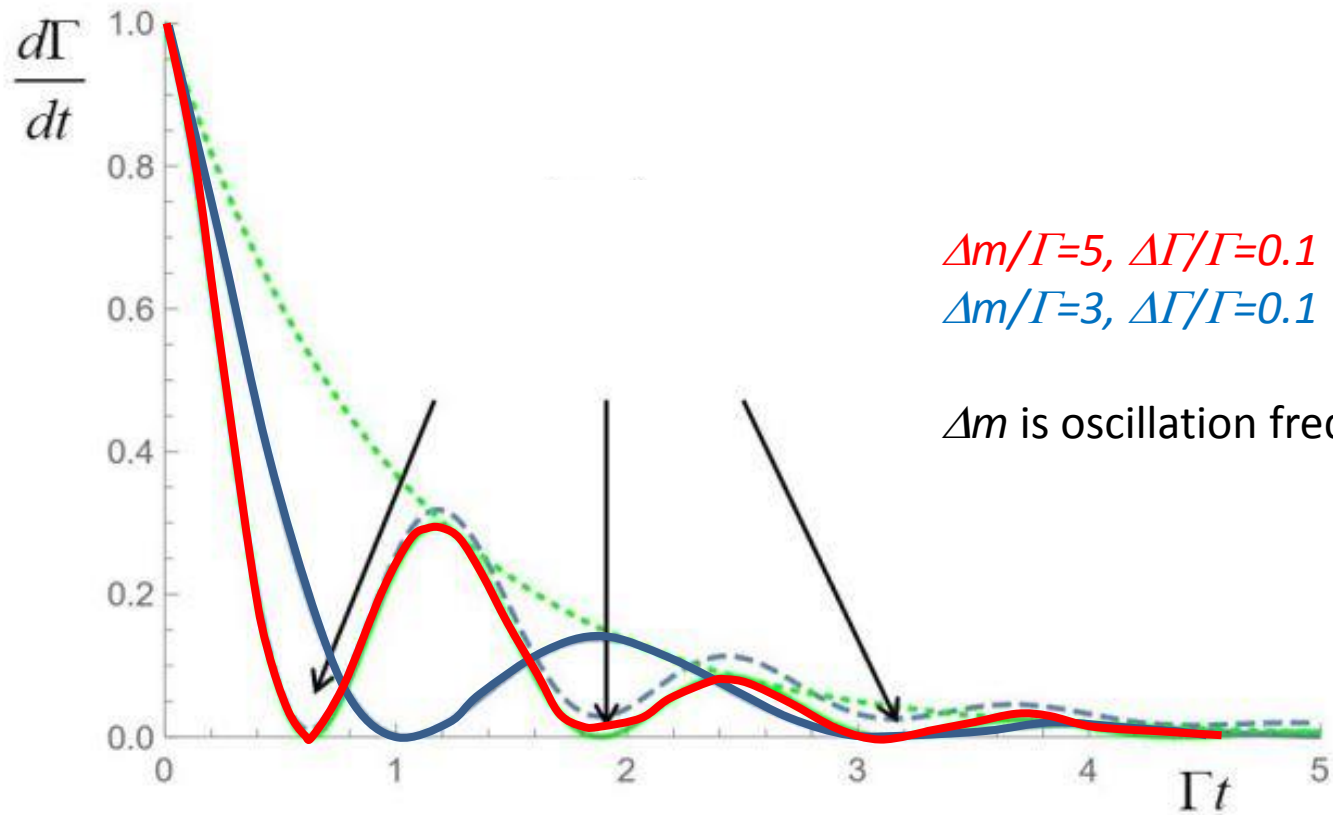
$$\frac{d\Gamma(P^0 \rightarrow f)}{dt} = \mathcal{N}_+ e^{-\Gamma t} \left[\cosh\left(\frac{\Delta\Gamma t}{2}\right) + \cos(\Delta m t) \right] |\langle f|P^0\rangle|^2$$



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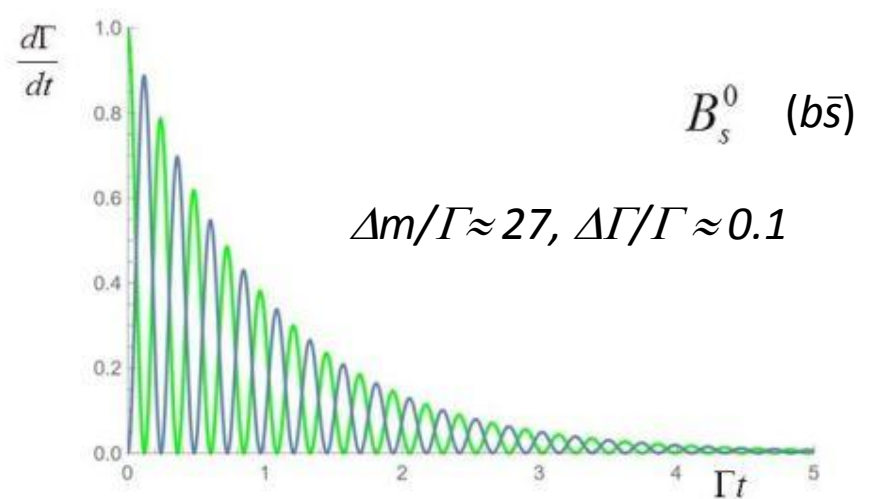
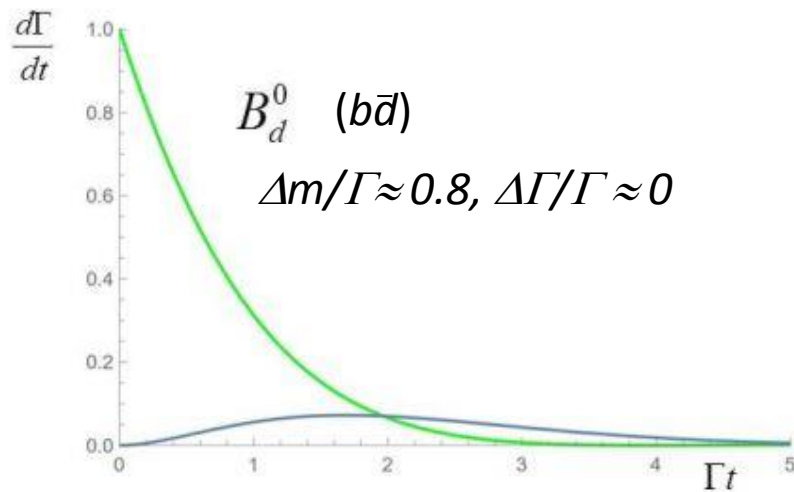
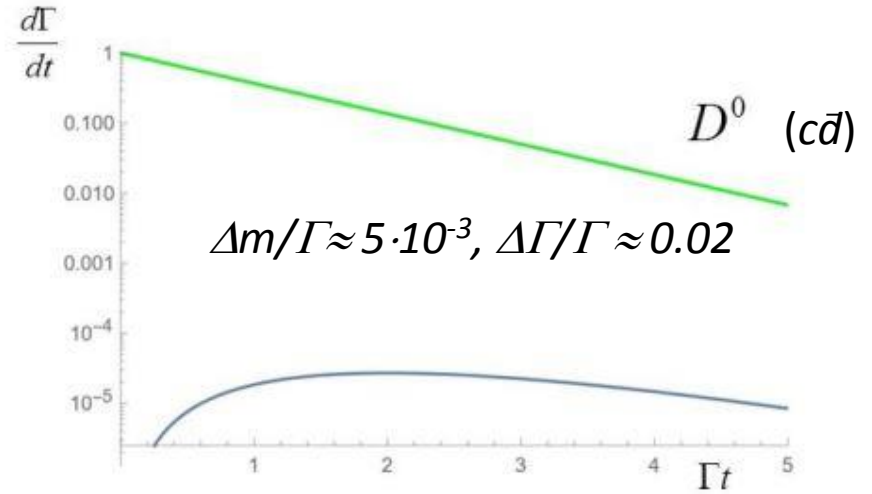
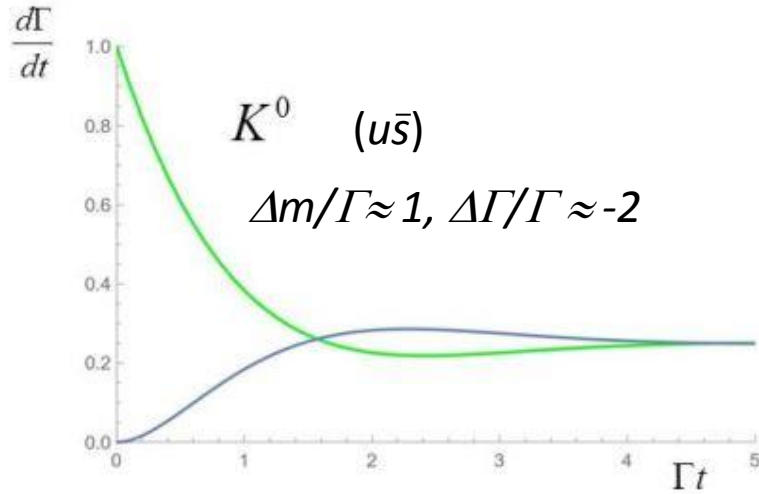
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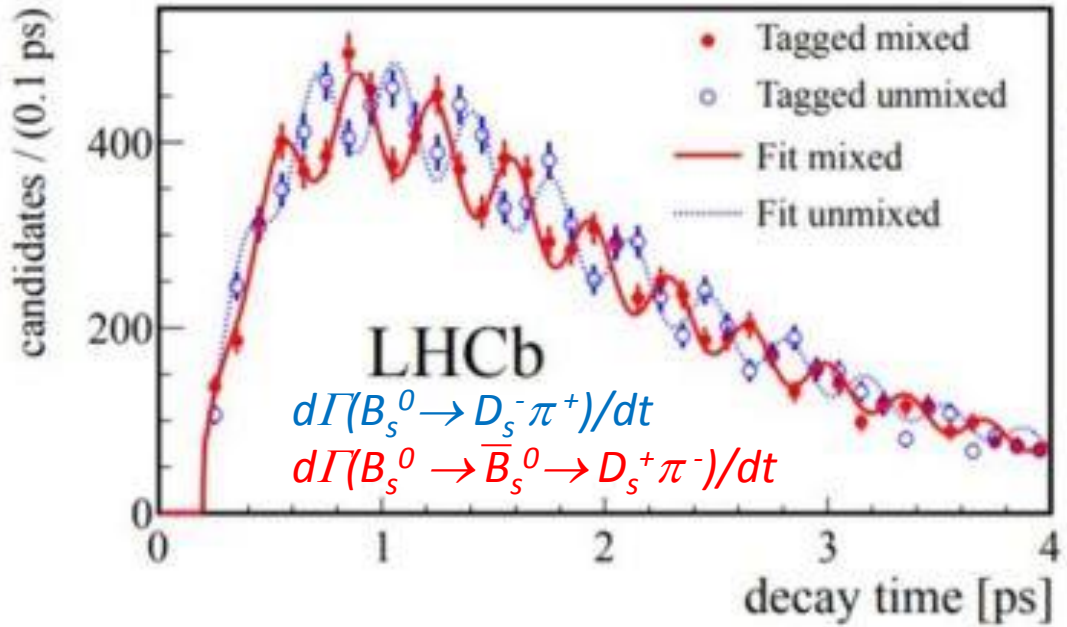


$$d\Gamma(P^0 \rightarrow f)/dt$$

for an initially produced P^0

$$d\Gamma(\bar{P}^0 \rightarrow \bar{f})/dt$$





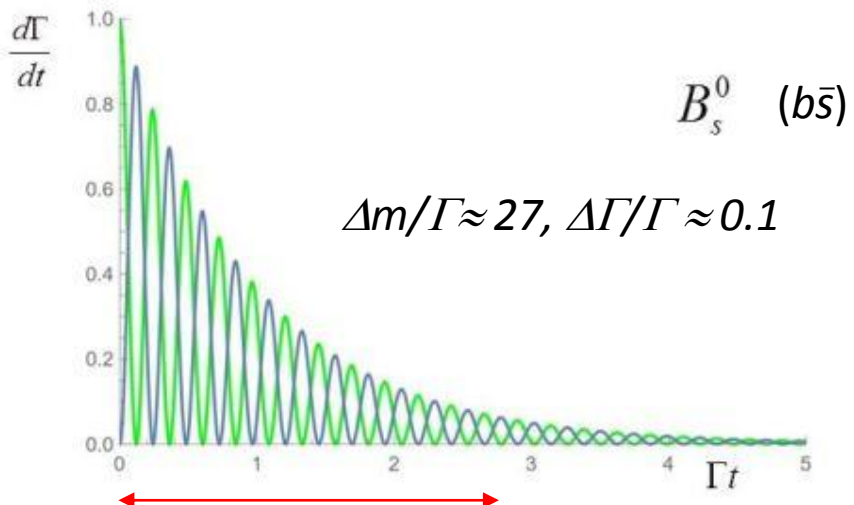
actual measurement

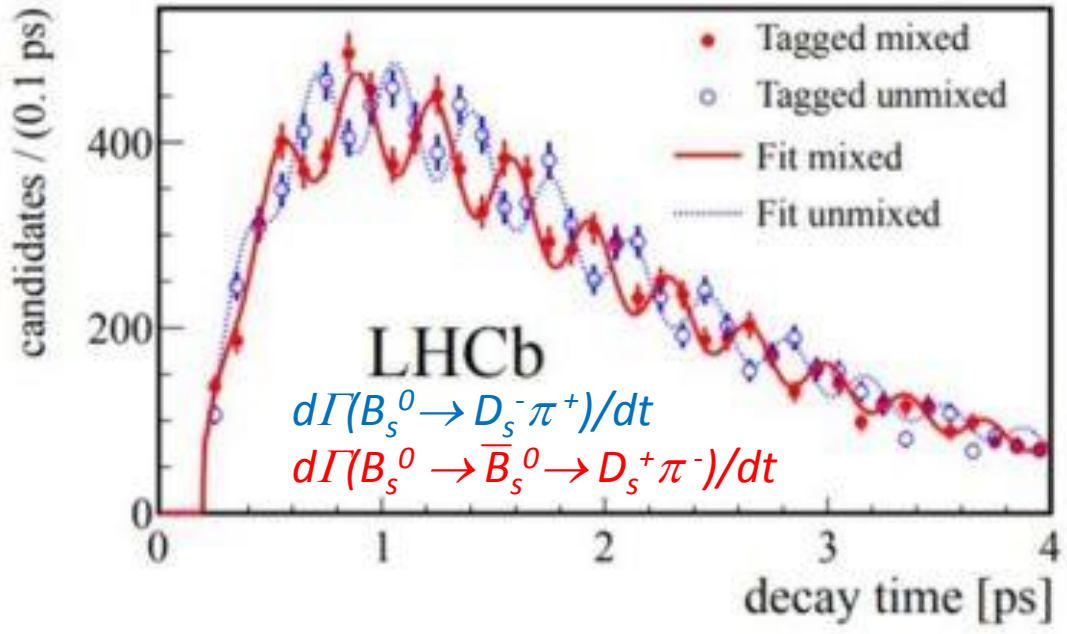


$$d\Gamma(P^0 \rightarrow f)/dt$$

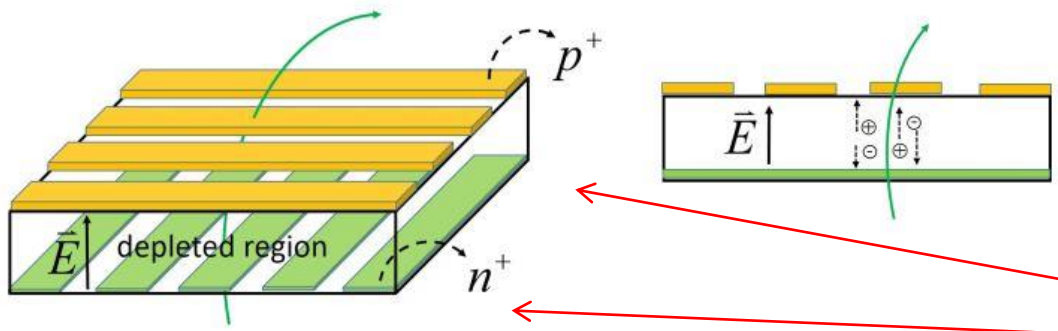
for an initially produced P^0

$$d\Gamma(\bar{P}^0 \rightarrow \bar{f})/dt$$





actual measurement



semiconductor detectors
 $\sigma(r, \phi) \sim \mathcal{O}(10 \mu\text{m})$



$$\mathcal{A}_{\text{flav}} = (N_{\text{unmix}}(t) - N_{\text{mix}}(t)) / (N_{\text{unmix}}(t) + N_{\text{mix}}(t)) = \frac{\cos(\Delta mt)}{\cosh\left(\frac{\Delta\Gamma t}{2}\right)}$$

$$\approx \cos(\Delta mt)$$

$$\Delta\Gamma \sim 0$$

$\mathcal{A}_{\text{flav}}$ for B_d^0

B. Aubert et al. (BaBar Coll.), Phys. Rev. Lett. 88, 221803 (2002)

